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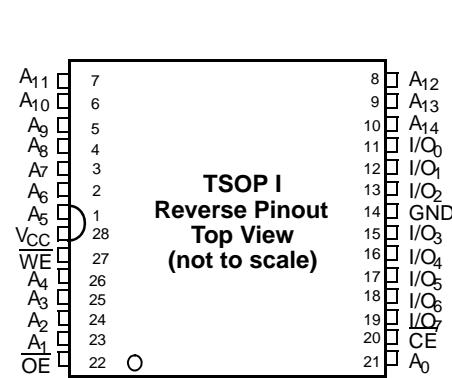
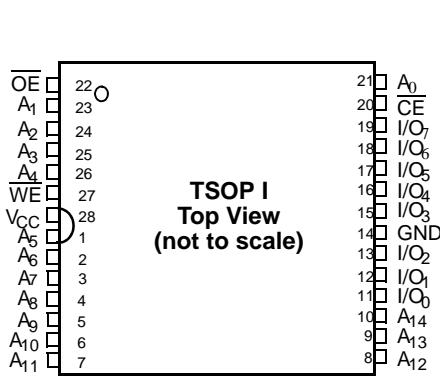
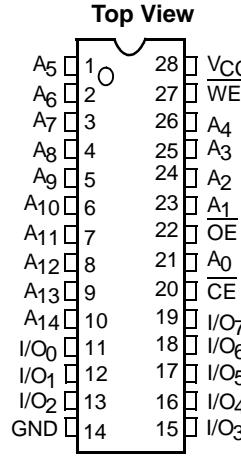
## Product Portfolio

Product	Range	V <sub>CC</sub> Range (V)			Power Dissipation			
		Min	Typ <sup>[1]</sup>	Max	Operating, I <sub>CC</sub> (mA)	Standby, I <sub>SB2</sub> (μA)	Typ <sup>[1]</sup>	Max
CY62256VNLL	Commercial	2.7	3.0	3.6	11	30	0.1	5
CY62256VNLL	Industrial	2.7	3.0	3.6	11	30	0.1	10
CY62256VNLL	Automotive-A	2.7	3.0	3.6	11	30	0.1	10
CY62256VNLL	Automotive-E	2.7	3.0	3.6	11	30	0.1	130

## Pin Configurations

Figure 1. 28-pin SOIC and 28-pin TSOP I pinouts

### Narrow SOIC



## Pin Definitions

Pin Number	Type	Description
1–10, 21, 23–26	Input	<b>A<sub>0</sub>–A<sub>14</sub></b> . Address inputs
11–13, 15–19	Input/Output	<b>I/O<sub>0</sub>–I/O<sub>7</sub></b> . Data lines. Used as input or output lines depending on operation.
27	Input/Control	<b>WE</b> . When selected LOW, a WRITE is conducted. When selected HIGH, a READ is conducted.
20	Input/Control	<b>CE</b> . When LOW, selects the chip. When HIGH, deselects the chip.
22	Input/Control	<b>OE</b> . Output Enable. Controls the direction of the I/O pins. When LOW, the I/O pins behave as outputs. When deasserted HIGH, I/O pins are tristated, and act as input data pins.
14	Ground	<b>GND</b> . Ground for the device
28	Power Supply	<b>V<sub>CC</sub></b> . Power supply for the device

### Note

1. Typical values are included for reference only and are not guaranteed or tested. Typical values are measured at V<sub>CC</sub> = V<sub>CC</sub> Typ, T<sub>A</sub> = 25 °C, and t<sub>AA</sub> = 70 ns.

## Maximum Ratings

Exceeding maximum ratings may shorten the useful life of the device. User guidelines are not tested.

Storage temperature .....	-65 °C to +150 °C
Ambient temperature with power applied .....	-55 °C to +125 °C
Supply voltage to ground potential (pin 28 to pin 14) [2] .....	-0.5 V to +4.6 V
DC voltage applied to outputs in high Z State [2] .....	-0.5 V to $V_{CC}$ + 0.5 V
DC input voltage [2] .....	-0.5 V to $V_{CC}$ + 0.5 V
Output current into outputs (LOW) .....	20 mA

Static discharge voltage  
 (per MIL-STD-883, method 3015) ..... > 2001 V  
 Latch-up current ..... > 200 mA

## Operating Range

Device	Range	Ambient Temperature ( $T_A$ ) [3]	$V_{CC}$
CY62256VN	Commercial	0 °C to +70 °C	2.7 V to 3.6 V
	Industrial	-40 °C to +85 °C	
	Automotive-A	-40 °C to +85 °C	
	Automotive-E	-40 °C to +125 °C	

## Electrical Characteristics

Over the Operating Range

Parameter	Description	Test Conditions	-70			Unit
			Min	Typ [4]	Max	
$V_{OH}$	Output HIGH voltage	$I_{OH} = -1.0 \text{ mA}$	$V_{CC} = 2.7 \text{ V}$	2.4	—	—
$V_{OL}$	Output LOW voltage	$I_{OL} = 2.1 \text{ mA}$	$V_{CC} = 2.7 \text{ V}$	—	—	0.4
$V_{IH}$	Input HIGH voltage			2.2	—	$V_{CC} + 0.3$
$V_{IL}$	Input LOW voltage			-0.5	—	0.8
$I_{IX}$	Input leakage current	$\text{GND} \leq V_{IN} \leq V_{CC}$	Commercial/ Industrial/ Automotive-A	-1	—	+1
			Automotive-E	-10	—	+10
$I_{OZ}$	Output leakage current	$\text{GND} \leq V_{IN} \leq V_{CC}$ , Output Disabled	Commercial/ Industrial/ Automotive-A	-1	—	+1
			Automotive-E	-10	—	+10
$I_{CC}$	$V_{CC}$ operating supply current	$V_{CC} = 3.6 \text{ V}$ , $I_{OUT} = 0 \text{ mA}$ , $f = f_{MAX} = 1/t_{RC}$	All ranges	—	11	30
$I_{SB1}$	Automatic CE power-down current - TTL inputs	$V_{CC} = 3.6 \text{ V}$ , $CE \geq V_{IH}$ , $V_{IN} \geq V_{IH}$ or $V_{IN} \leq V_{IL}$ , $f = f_{MAX}$	All ranges	—	100	300
$I_{SB2}$	Automatic CE power-down current - CMOS inputs	$V_{CC} = 3.6 \text{ V}$ , $CE \geq V_{CC} - 0.3 \text{ V}$ , $V_{IN} \geq V_{CC} - 0.3 \text{ V}$ or $V_{IN} \leq 0.3 \text{ V}$ , $f = 0$	Commercial	—	0.1	5
			Industrial/ Automotive-A	—		10
			Automotive-E	—		130

### Notes

2.  $V_{IL}$  (min) = -2.0 V for pulse durations of less than 20 ns.
3.  $T_A$  is the "Instant-On" case temperature.
4. Typical values are included for reference only and are not guaranteed or tested. Typical values are measured at  $V_{CC} = V_{CC}$  Typ,  $T_A = 25 \text{ }^\circ\text{C}$ , and  $t_{AA} = 70 \text{ ns}$ .

## Capacitance

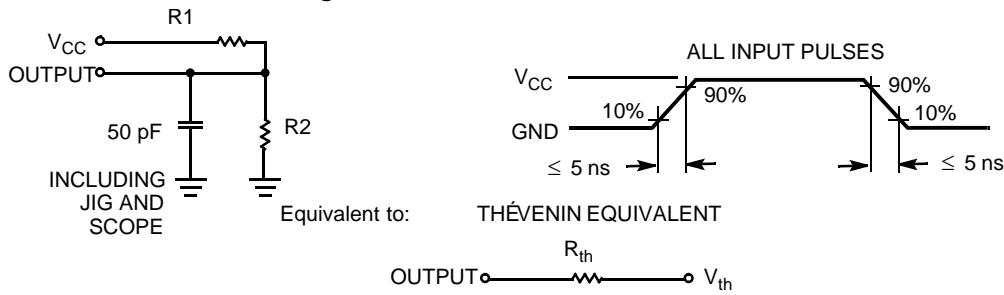
Parameter [5]	Description	Test Conditions	Max	Unit
$C_{IN}$	Input capacitance	$T_A = 25^\circ\text{C}$ , $f = 1 \text{ MHz}$ , $V_{CC} = 3.0 \text{ V}$	6	pF
$C_{OUT}$	Output capacitance		8	pF

## Thermal Resistance

Parameter [5]	Description	Test Conditions	SOIC	TSOPI	RTSOP	Unit
$\theta_{JA}$	Thermal resistance (junction to ambient)	Still air, soldered on a 3 x 4.5 inch, two-layer printed circuit board	68.45	87.62	87.62	°C/W
$\theta_{JC}$	Thermal resistance (junction to case)		26.94	23.73	23.73	°C/W

## AC Test Loads and Waveforms

Figure 2. AC Test Loads and Waveforms



Parameter	Value	Units
R1	1100	Ohms
R2	1500	Ohms
R <sub>TH</sub>	645	Ohms
V <sub>TH</sub>	1.750	Volts

### Note

5. Tested initially and after any design or process changes that may affect these parameters.

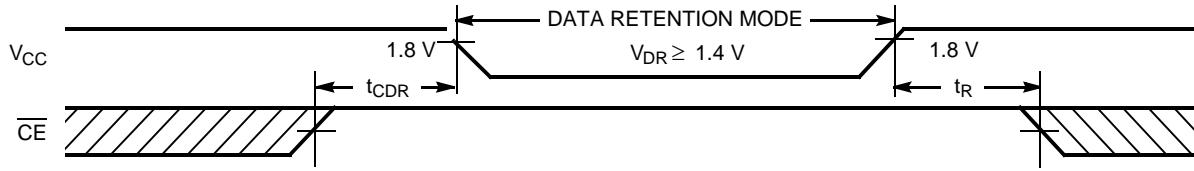
## Data Retention Characteristics

Over the Operating Range

Parameter	Description	Conditions <sup>[6]</sup>			Min	Typ <sup>[7]</sup>	Max	Unit
V <sub>DR</sub>	V <sub>CC</sub> for data retention				1.4	—	—	V
I <sub>CCDR</sub>	Data retention current	V <sub>CC</sub> = 1.4 V, CE ≥ V <sub>CC</sub> − 0.3 V, V <sub>IN</sub> ≥ V <sub>CC</sub> − 0.3 V or V <sub>IN</sub> ≤ 0.3 V	Commercial	—	0.1	3	μA	
			Industrial/ Automotive-A	—		6		
			Automotive-E	—		50		
t <sub>CDR</sub> <sup>[6]</sup>	Chip deselect to data retention time				0	—	—	ns
t <sub>R</sub> <sup>[8]</sup>	Operation recovery time				70	—	—	ns

## Data Retention Waveform

Figure 3. Data Retention Waveform



### Notes

6. No input may exceed V<sub>CC</sub> + 0.3 V.
7. Typical values are included for reference only and are not guaranteed or tested. Typical values are measured at V<sub>CC</sub> = V<sub>CC</sub> Typ, T<sub>A</sub> = 25 °C, and t<sub>AA</sub> = 70 ns.
8. Tested initially and after any design or process changes that may affect these parameters.

## Switching Characteristics

Over the Operating Range

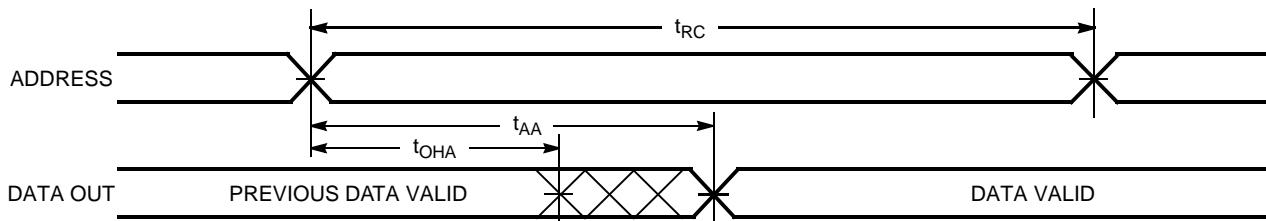
Parameter [9]	Description	CY62256VN-70		Unit
		Min	Max	
<b>Read Cycle</b>				
$t_{RC}$	Read cycle time	70	—	ns
$t_{AA}$	Address to data valid	—	70	ns
$t_{OHA}$	Data hold from address change	10	—	ns
$t_{ACE}$	$\overline{CE}$ LOW to data valid	—	70	ns
$t_{DOE}$	$\overline{OE}$ LOW to data valid	—	35	ns
$t_{LZOE}$	$\overline{OE}$ LOW to low Z <sup>[10]</sup>	5	—	ns
$t_{HZOE}$	$\overline{OE}$ HIGH to high Z <sup>[10, 11]</sup>	—	25	ns
$t_{LZCE}$	$\overline{CE}$ LOW to low Z <sup>[10]</sup>	10	—	ns
$t_{HZCE}$	$\overline{CE}$ HIGH to high Z <sup>[10, 11]</sup>	—	25	ns
$t_{PU}$	$\overline{CE}$ LOW to power-up	0	—	ns
$t_{PD}$	$\overline{CE}$ HIGH to power-down	—	70	ns
<b>Write Cycle</b> [12, 13]				
$t_{WC}$	Write cycle time	70	—	ns
$t_{SCE}$	$\overline{CE}$ LOW to write end	60	—	ns
$t_{AW}$	Address setup to write end	60	—	ns
$t_{HA}$	Address hold from write end	0	—	ns
$t_{SA}$	Address setup to write start	0	—	ns
$t_{PWE}$	$\overline{WE}$ pulse width	50	—	ns
$t_{SD}$	Data setup to write end	30	—	ns
$t_{HD}$	Data hold from write end	0	—	ns
$t_{HZWE}$	$\overline{WE}$ LOW to high Z <sup>[10, 11]</sup>	—	25	ns
$t_{LZWE}$	$\overline{WE}$ HIGH to low Z <sup>[10]</sup>	10	—	ns

### Notes

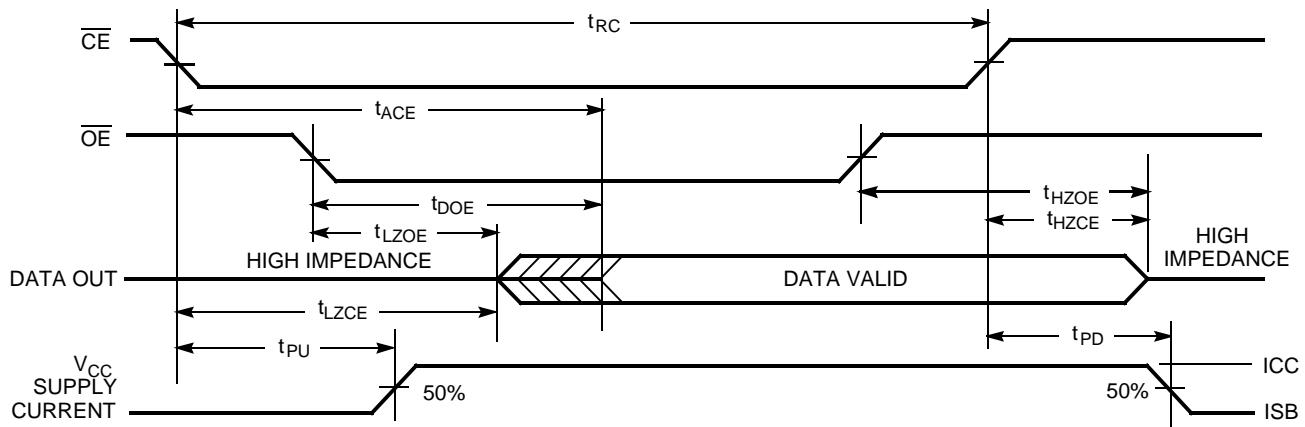
9. Test conditions assume signal transition time of 5 ns or less timing reference levels of  $V_{CC}/2$ , input pulse levels of 0 to  $V_{CC}$ , and output loading of the specified  $I_{OL}/I_{OH}$  and 100-pF load capacitance.
10. At any temperature and voltage condition,  $t_{HZCE}$  is less than  $t_{LZCE}$ ,  $t_{HZOE}$  is less than  $t_{LZOE}$ , and  $t_{HZWE}$  is less than  $t_{LZWE}$  for any device.
11.  $t_{HZOE}$ ,  $t_{HZCE}$ , and  $t_{HZWE}$  are specified with  $C_L = 5$  pF as in (b) of AC Test Loads. Transition is measured  $\pm 200$  mV from steady-state voltage.
12. The internal write time of the memory is defined by the overlap of  $CE$  LOW and  $WE$  LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.
13. The minimum write cycle time for Write Cycle No. 3 ( $\overline{WE}$  Controlled,  $\overline{OE}$  LOW) is the sum of  $t_{HZWE}$  and  $t_{SD}$ .

## Switching Waveforms

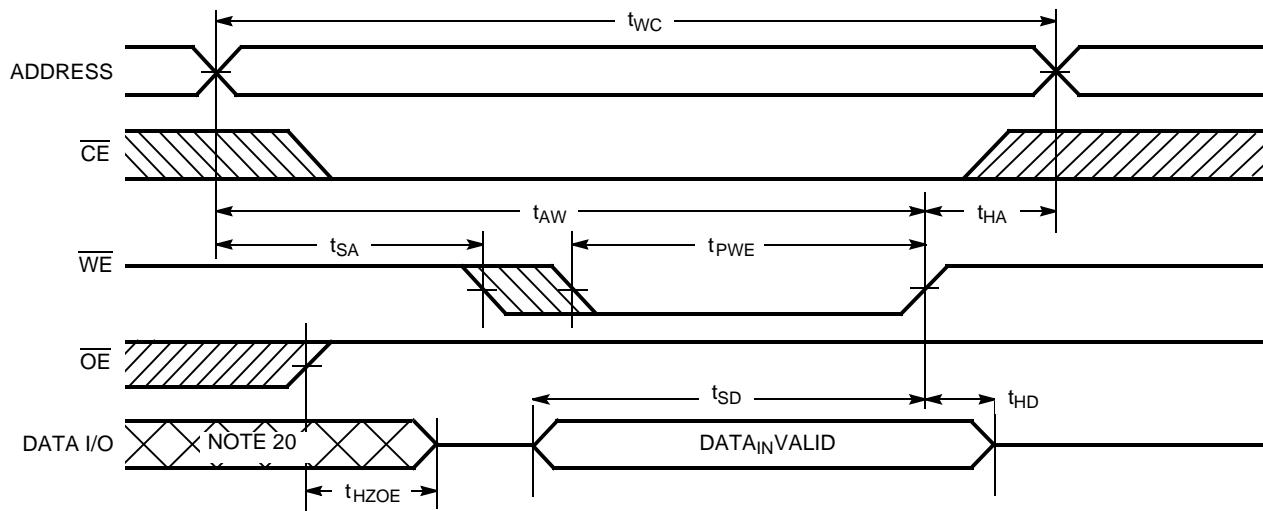
**Figure 4. Read Cycle No. 1** [14, 15]



**Figure 5. Read Cycle No. 2** [15, 16]



**Figure 6. Write Cycle No. 1 ( $\overline{WE}$  Controlled)** [17, 18, 19]

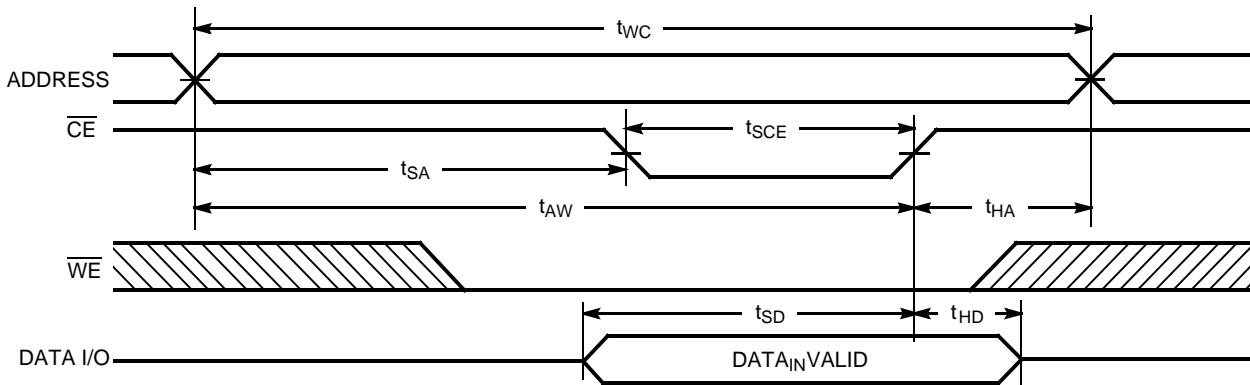


### Notes

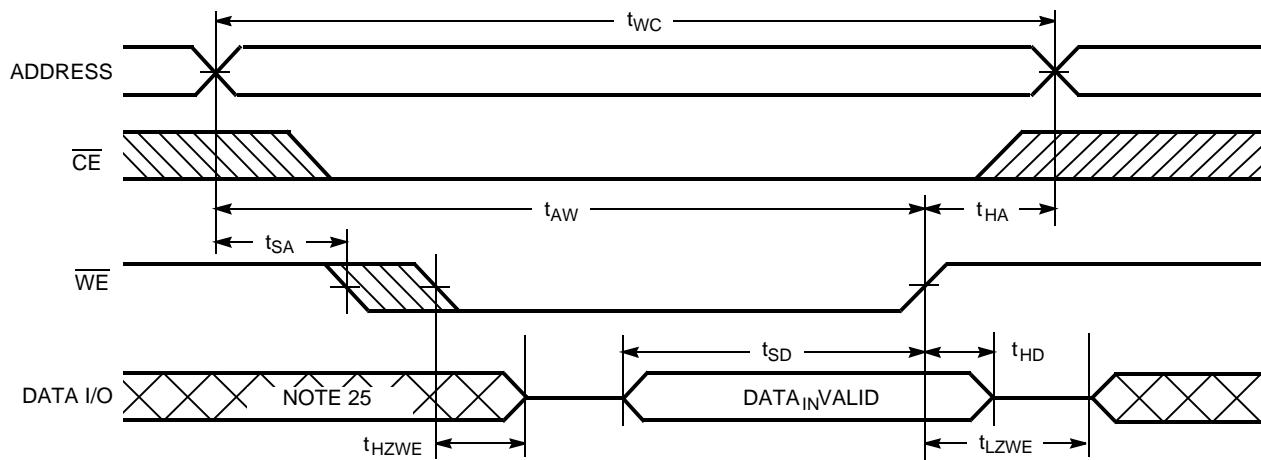
14. Device is continuously selected.  $\overline{OE}, \overline{CE} = V_{IL}$ .
15.  $\overline{WE}$  is HIGH for read cycle.
16. Address valid prior to or coincident with  $\overline{CE}$  transition LOW.
17. The internal write time of the memory is defined by the overlap of  $\overline{CE}$  LOW and  $\overline{WE}$  LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.
18. Data I/O is high impedance if  $\overline{OE} = V_{IL}$ .
19. If  $\overline{CE}$  goes HIGH simultaneously with  $\overline{WE}$  HIGH, the output remains in a high impedance state.
20. During this period, the I/Os are in output state and input signals should not be applied.

## Switching Waveforms (continued)

**Figure 7. Write Cycle No. 2 ( $\overline{CE}$  Controlled) [21, 22, 23]**



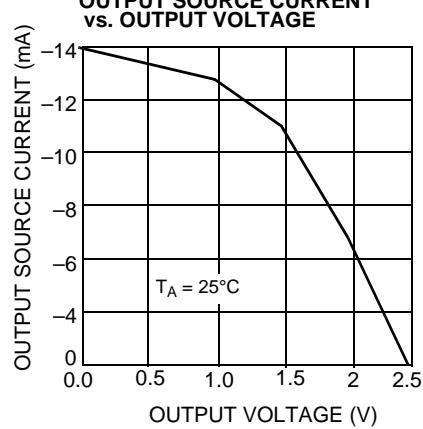
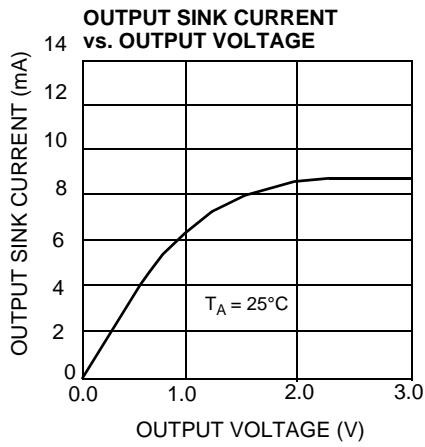
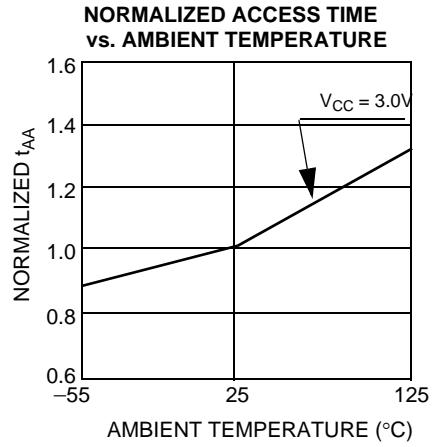
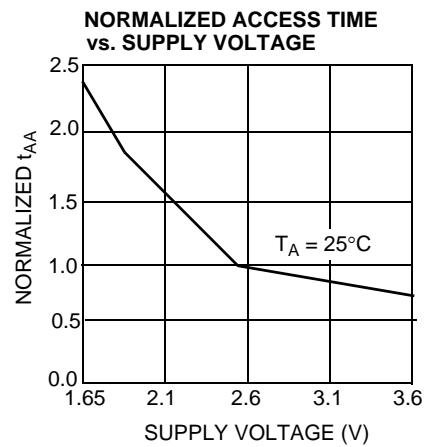
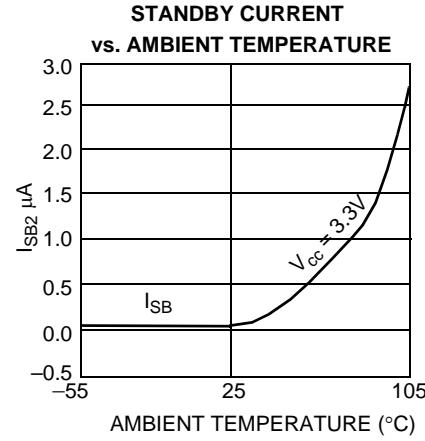
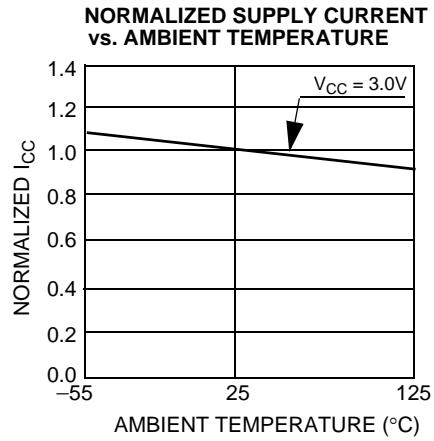
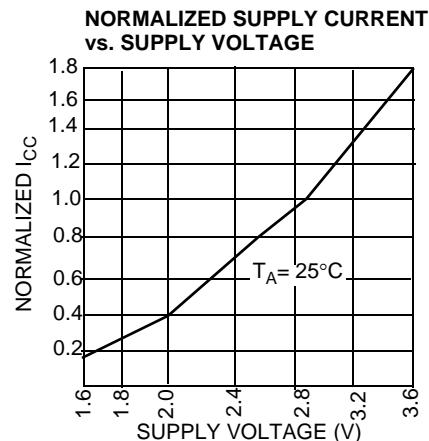
**Figure 8. Write Cycle No. 3 ( $\overline{WE}$  Controlled,  $\overline{OE}$  LOW) [23, 24]**



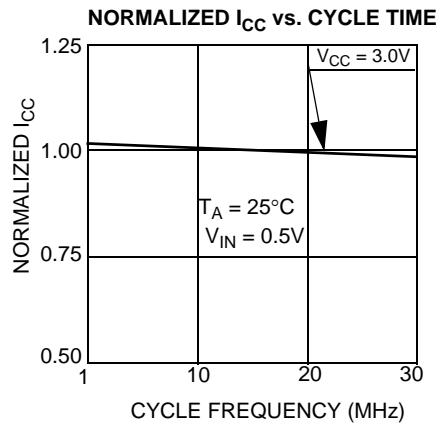
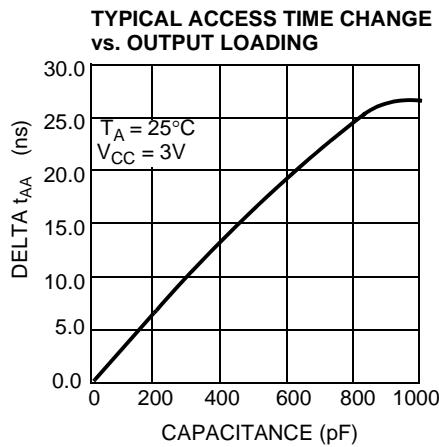
### Notes

21. The internal write time of the memory is defined by the overlap of  $\overline{CE}$  LOW and  $\overline{WE}$  LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.
22. Data I/O is high impedance if  $OE = V_{IH}$ .
23. If  $CE$  goes HIGH simultaneously with  $WE$  HIGH, the output remains in a high impedance state.
24. The minimum write cycle time for write cycle No. 3 (WE Controlled,  $OE$  LOW) is the sum of  $t_{HZWE}$  and  $t_{SD}$ .
25. During this period, the I/Os are in output state and input signals should not be applied.

## Typical DC and AC Characteristics



## Typical DC and AC Characteristics (continued)



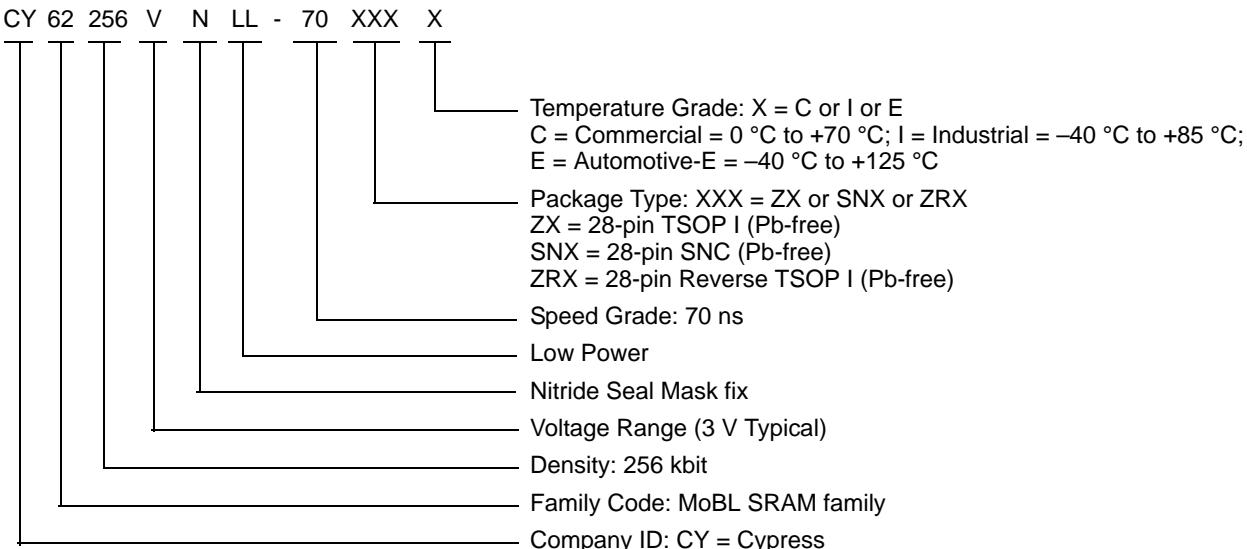
## Truth Table

<b>CE</b>	<b>WE</b>	<b>OE</b>	<b>Inputs/Outputs</b>	<b>Mode</b>	<b>Power</b>
H	X	X	High Z	Deselect/power-down	Standby ( $I_{SB}$ )
L	H	L	Data out	Read	Active ( $I_{CC}$ )
L	L	X	Data in	Write	Active ( $I_{CC}$ )
L	H	H	High Z	Deselect, output disabled	Active ( $I_{CC}$ )

## Ordering Information

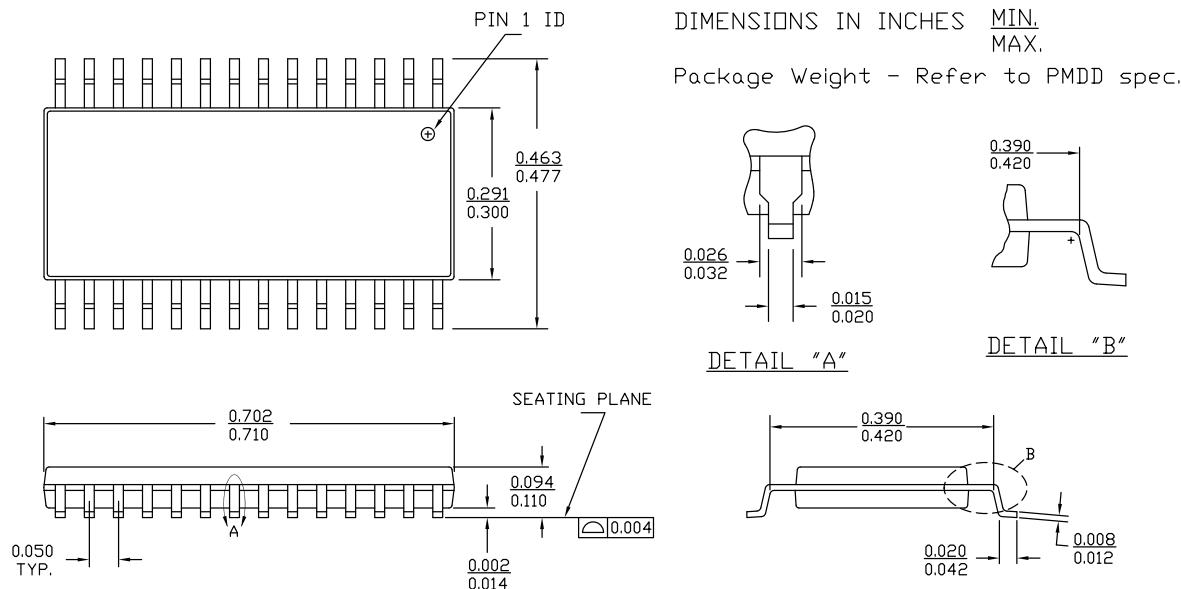
Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
70	CY62256VNLL-70ZXC	51-85071	28-pin TSOP I (Pb-free)	Commercial
	CY62256VNLL-70SNXI	51-85092	28-pin SNC (300 Mils) Narrow Body (Pb-free)	Industrial
	CY62256VNLL-70ZXI	51-85071	28-pin TSOP I (Pb-free)	
	CY62256VNLL-70ZRXI	51-85074	28-pin Reverse TSOP I (Pb-free)	
	CY62256VNLL-70SNXE	51-85092	28-pin SNC (300 Mils) Narrow Body (Pb-free)	Automotive-E
	CY62256VNLL-70ZXE	51-85071	28-pin TSOP I (Pb-free)	

## Ordering Code Definitions



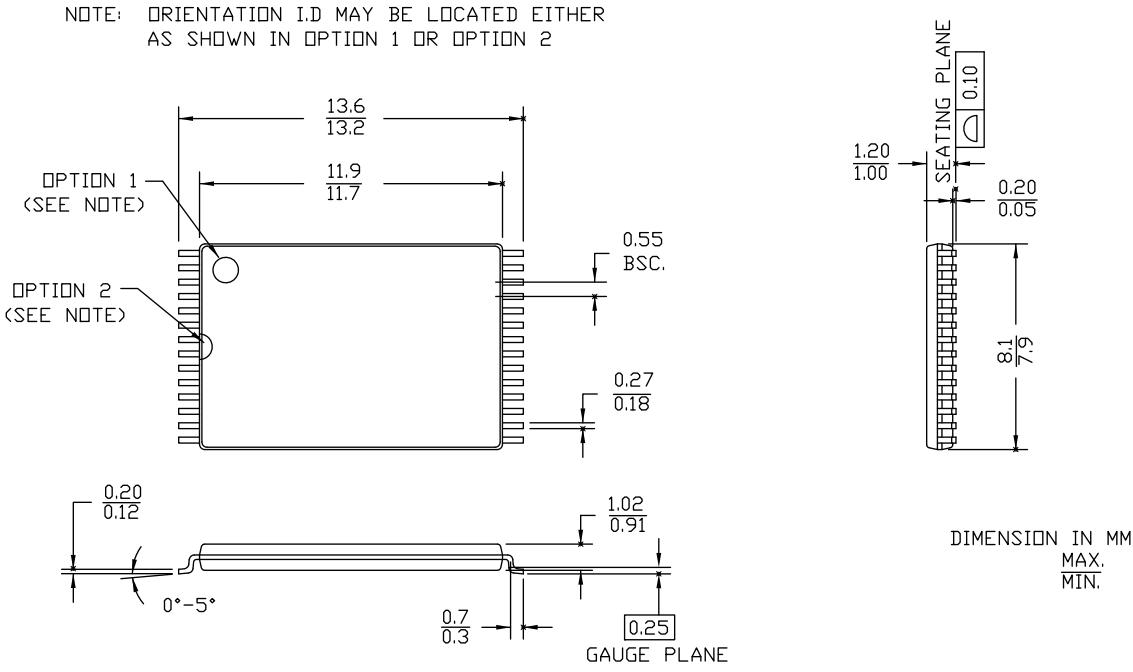
## Package Diagrams

**Figure 9. 28-pin SNC (300 Mil) SN28.3 (Narrow Body) Package Outline, 51-85092**



51-85092 \*E

**Figure 10. 28-pin TSOP 1 (8 × 13.4 × 1.2 mm) Z28 (Standard) Package Outline, 51-85071**

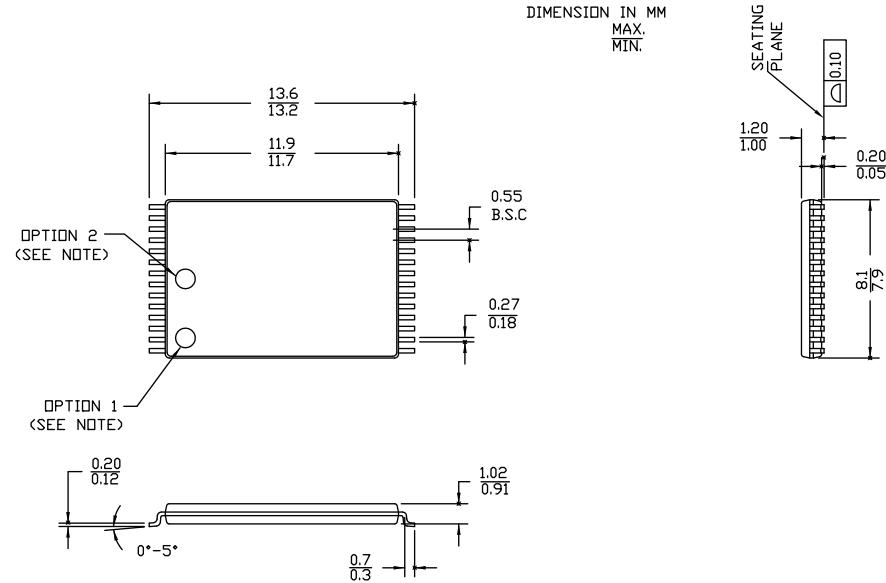


51-85071 \*J

## Package Diagrams

Figure 11. 28-pin TSOP I (8 x 13.4 mm) Package Outline - Reverse, 51-85074

NOTE: ORIENTATION ID MAY BE LOCATED EITHER AS SHOWN IN OPTION 1 OR OPTION 2



51-85074 \*H

## Acronyms

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
I/O	Input/Output
SRAM	Static Random Access Memory
TSOP	Thin Small Outline Package
VFBGA	Very Fine-Pitch Ball Grid Array

## Document Conventions

### Units of Measure

Symbol	Unit of Measure
°C	degree Celsius
µA	microampere
mA	milliampere
MHz	megahertz
ns	nanosecond
Ω	ohm
pF	picofarad
V	volt
W	watt

## Document History Page

Document Title: CY62256VN, 256-Kbit (32 K × 8) Static RAM Document Number: 001-06512				
Revision	ECN	Orig. of Change	Submission Date	Description of Change
**	426504	NXR	See ECN	New data sheet
*A	488954	NXR	See ECN	Added Automotive product Updated ordering Information table
*B	2769239	VKN / AESA	09/25/09	Corrected $V_{IL}$ description in the Electrical Characteristics table
*C	2901521	AJU	03/30/2010	Removed inactive parts from Ordering Information. Updated Package Diagram.
*D	3119519	AJU	01/04/2011	Updated Ordering Information. Added <a href="#">Ordering Code Definitions</a> .
*E	3329873	RAME	07/27/11	Updated template and styles according to current Cypress standards. Added acronyms and units. Removed reference to AN1064 SRAM system guidelines. Updated operation recovery time parameter under <a href="#">Data Retention Characteristics on page 6</a> .
*F	4122787	VINI	09/13/2013	Updated <a href="#">Package Diagrams</a> : spec 51-85092 – Changed revision from *C to *E. Updated in new template. Completing Sunset Review.
*G	4525875	VINI	10/06/2014	Updated <a href="#">Maximum Ratings</a> : Referred Note 2 in "Supply voltage to ground potential (pin 28 to pin 14)". Updated <a href="#">Package Diagrams</a> : spec 51-85071 – Changed revision from *I to *J. spec 51-85074 – Changed revision from *G to *H. Completing Sunset Review.
*H	4576406	VINI	01/16/2015	Added related documentation hyperlink in page 1. Added Note 13 in <a href="#">Switching Characteristics</a> . Added note reference 13 in the <a href="#">Switching Characteristics</a> table.

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